

74VHC08 • 74VHCT08 Quad 2-Input AND Gate

General Description

The VHC/VHCT08 is an advanced high speed CMOS 2 Input AND Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 4 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- Low power dissipation:
 $I_{CC} = 2 \mu A$ (Max) @ $T_A = 25^\circ C$
- High Speed:
 $t_{pd} = 4.3$ ns (typ) at $T_A = 25^\circ C$
- High noise immunity:
VHC $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
VHCT $V_{IH} = 2.0V$, $V_{IL} = 0.8V$
- Power down protection:
VHC inputs only
VHCT inputs and outputs
- Low noise:
 $V_{OLP} = 0.8V$ (max)
- Pin and function compatible with 74HC/HCT08

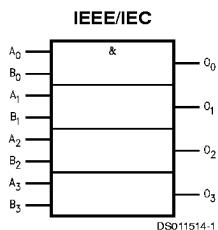
Note: Add external pull up resistor to VHCT outputs to drive CMOS inputs.

Ordering Code:

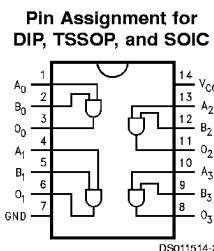
Commercial	Package Number	Package Description
74VHC08M	M14A	14-Lead Molded JEDEC SOIC
74VHC08SJ	M14D	14-Lead Molded EIAJ SOIC
74VHC08MTC	MTC14	14-Lead Molded JEDEC Type 1 TSSOP
74VHC08N	N14A	14-Lead Molded DIP
74VHCT08M	M14A	14-Lead Molded JEDEC SOIC
74VHCT08SJ	M14D	14-Lead Molded EIAJ SOIC
74VHCT08MTC	MTC14	14-Lead Molded JEDEC Type 1 TSSOP
74VHCT08N	N14A	14-Lead Molded DIP

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A _n , B _n	Inputs
O _n	Outputs

Truth Table

A	B	O
L	L	L
L	H	L
H	L	L
H	H	H

Absolute Maximum Ratings (Note 1)						Recommended Operating Conditions (Note 3)		
Symbol	Parameter	V _{CC} (V)	T _A = 25°C		T _A = -40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min		
V _{IH}	High Level Input Voltage	2.0 3.0–5.5	1.50 0.7 V _{CC}			1.50 0.7 V _{CC}	V	
V _{IL}	Low Level Input Voltage	2.0 3.0–5.5		0.50 0.3 V _{CC}		0.50 0.3 V _{CC}	V	
V _{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9	V	V _{IN} = V _{IH} or V _{IL} I _{OH} = -50 μA
		3.0	2.9	3.0		2.9		I _{OH} = -4 mA
		4.5	4.4	4.5		4.4	V	I _{OH} = -8 mA
		3.0	2.58			2.48		
V _{OL}	Low Level Output Voltage	2.0		0.0	0.1	0.1	V	V _{IN} = V _{IH} or V _{IL} I _{OL} = 50 μA
		3.0		0.0	0.1	0.1		I _{OL} = 4 mA
		4.5		0.0	0.1	0.1	V	I _{OL} = 8 mA
		3.0		0.36		0.44		
I _{IN}	Input Leakage Current	0–5.5		±0.1		±1.0	μA	V _{IN} = 5.5V or GND
	Quiescent Supply Current	5.5		2.0		20.0	μA	V _{IN} = V _{CC} or GND

Noise Characteristics for VHC						
Symbol	Parameter	V _{CC} (V)	T _A = 25°C		Units	Conditions
			Typ	Limits		
V _{OLP} (Note 4)	Quiet Output Maximum Dynamic V _{OL}	5.0	0.3	0.8	V	C _L = 50 pF
V _{OLV} (Note 4)	Quiet Output Minimum Dynamic V _{OL}	5.0	-0.3	-0.8	V	C _L = 50 pF
V _{IHP} (Note 4)	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	C _L = 50 pF
V _{ILD} (Note 4)	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	C _L = 50 pF

Note 4: Parameter guaranteed by design.

DC Electrical Characteristics for VHCT

Symbol	Parameter	V _{CC} (V)	T _A = 25°C			T _A = -40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
V _{IH}	High Level Input Voltage	4.5 5.5	2.0 2.0			2.0 2.0		V	
V _{IL}	Low Level Input Voltage	4.5 5.5			0.8 0.8		0.8 0.8	V	
V _{OH}	High Level Output Voltage	4.5	3.15	3.65		3.15		V	V _{IN} = V _{IH} or V _{IL}
		4.5	2.5			2.4		V	
V _{OL}	Low Level Output Voltage	4.5		0.0	0.1		0.1	V	V _{IN} = V _{IH} or V _{IL}
		4.5		0.36			0.44	V	
I _{IN}	Input Leakage Current	0–5.5		±0.1		±1.0		µA	V _{IN} = 5.5V or GND
I _{CC}	Quiescent Supply Current	5.5		2.0		20.0		µA	V _{IN} = V _{CC} or GND
I _{CC} T	Maximum I _{CC} / Input	5.5		1.35		1.50		mA	V _{IN} = 3.4V Other Inputs = V _{CC} or GND
I _{OFF}	Output Leakage Current (Power Down State)	0.0		0.5		5.0		µA	V _{OUT} = 5.5V

Noise Characteristics for VHCT

Symbol	Parameter	V _{CC} (V)	T _A = 25°C		Units	Conditions
			Typ	Limit		
V _{OLP} (Note 5)	Quiet Output Maximum Dynamic V _{OL}		0.4	0.8	V	C _L = 50 pF
V _{OLV} (Note 5)	Quiet Output Minimum Dynamic V _{OL}		-0.4	-0.8	V	C _L = 50 pF
V _{IHD} (Note 5)	Minimum High Level Dynamic Input Voltage			2.0	V	C _L = 50 pF
V _{ILD} (Note 5)	Maximum Low Level Dynamic Input Voltage			0.8	V	C _L = 50 pF

Note 5: Parameter guaranteed by design.

AC Electrical Characteristics for VHCT

Symbol	Parameter	V _{CC} (V)	T _A = 25°C			T _A = -40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t _{PHL} , t _{PLH}	Propagation Delay	3.3±0.3		6.2	8.8	1.0	10.5	ns	C _L = 15 pF
				8.7	12.3	1.0	14.0		C _L = 50 pF
		5.0±0.5		4.3	5.9	1.0	7.0	ns	C _L = 15 pF
				5.8	7.9	1.0	9.0		C _L = 50 pF
C _{IN}	Input Capacitance			4	10		10	pF	V _{CC} = Open
C _{PD}	Power Dissipation Capacitance			18				pF	(Note 6)

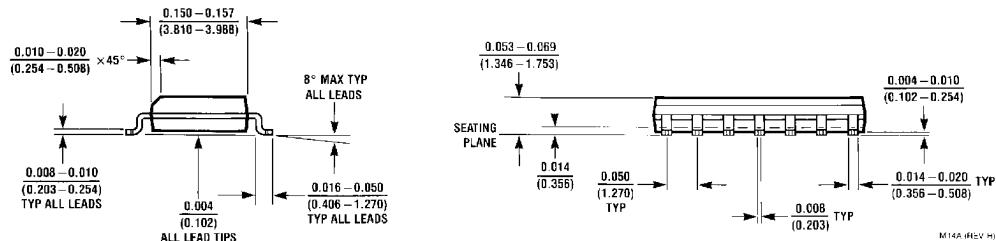
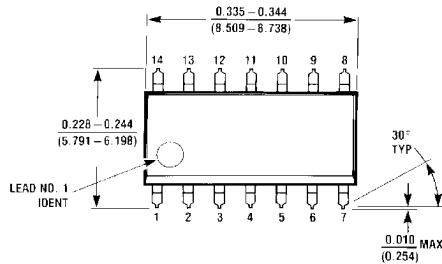
Note 6: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per gate).

AC Electrical Characteristics for VHCT

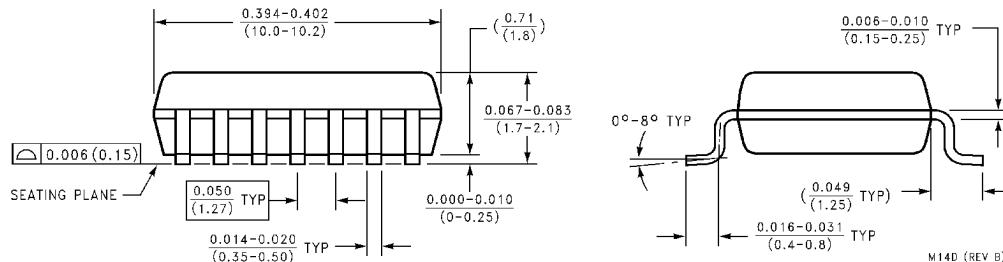
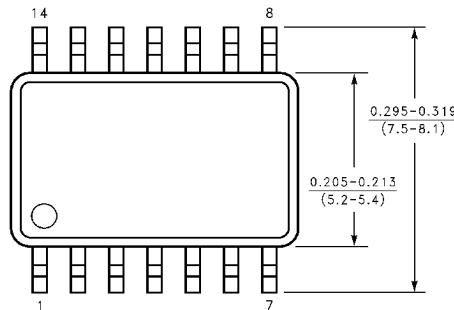
Symbol	Parameter	V _{CC} (V)	T _A = 25°C			T _A = -40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
t _{PLH}	Propagation Delay	5.0	5.0	6.9	8.0	1.0	9.0	ns	C _L = 15 pF
t _{PHL}		±0.5	5.5	7.9	9.0				C _L = 50 pF
C _{IN}	Input Capacitance		4	10		10		pF	V _{CC} = Open
C _{PD}	Power Dissipation Capacitance		18					pF	(Note 7)

Note 7: C_{PD} is defined as the value of the internal equivalent capacitance, which is calculated from the operating current consumption without load. Average operating current can be obtained from the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/4 (per gate)

Physical Dimensions inches (millimeters) unless otherwise noted

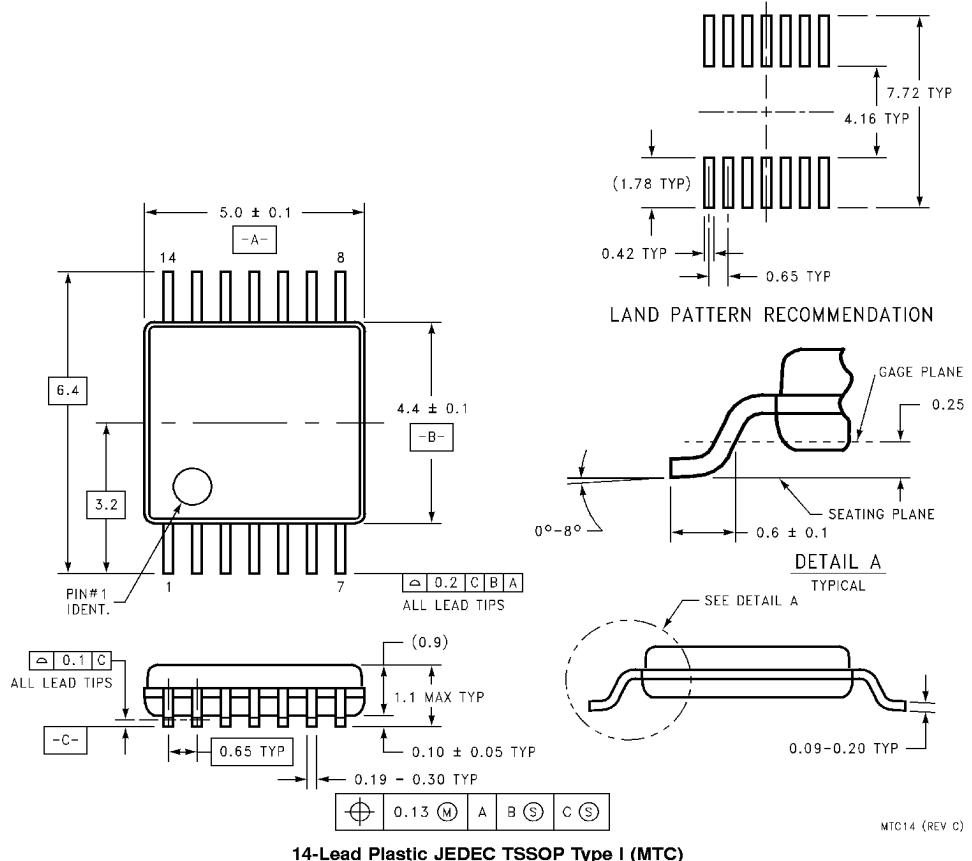


14-Lead Small Outline Integrated Circuit—JEDEC SOIC (M)
Package Number M14A



14-Lead Plastic EIAJ SOIC (SJ)
Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

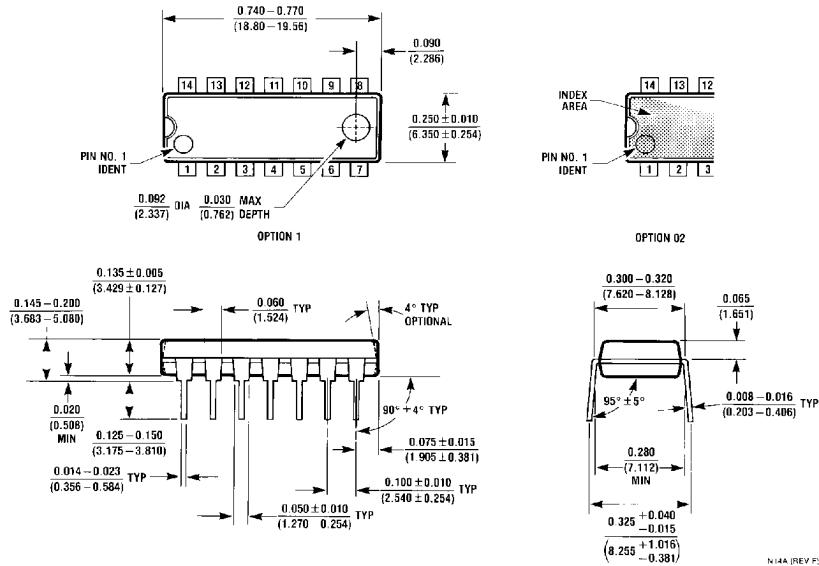


14-Lead Plastic JEDEC TSSOP Type I (MTC)
Package Number MTC14

MTC14 (REV C)

74VHC08 • 74VHCT08 Quad 2-Input AND Gate

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Molded Dual-In-Line Package (MDIP)
Package Number N14A

N14A (REV F)

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